

ON Semiconductor®

FDD8445-F085

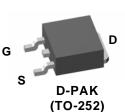
N-Channel PowerTrench® MOSFET 40V, 50A, 6.7m Ω Features

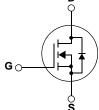
- Typ $R_{DS(on)} = 6.7 \text{m}\Omega$ at $V_{GS} = 10 \text{V}$, $I_D = 50 \text{A}$
- Typ $Q_{q(10)} = 45nC$ at $V_{GS} = 10V$, $I_D = 50A$
- Low Miller Charge
- Low Qrr Body Diode
- UIS Capability (Single Pulse/ Repetitive Pulse)
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V Systems







MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	40	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current Continuous (V _{GS} = 10V)	50	^
ID	Pulsed	Figure 4	A
E _{AS}	Single Pulse Avalanche Energy (Note 1)	144	mJ
5	Power Dissipation	79	W
P_D	Derate above 25°C	0.53	W/°C
T _J , T _{STG}	Operating and Storage Temperature	-55 to +175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case	1.9	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient, 1in ² copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8445 FD	DD8445-F085	TO-252AA	13"	12mm	2500 units

1: Starting T_J = 25°C, L = 0.18mH, I_{AS} = 40A 2: A suffix as "...F085P" has been temporarily introduced in order to manage a double source strategy as ON Semiconductor has officially announced in Aug 2014.

Units

Max

Тур

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Parameter

Off Characteristics							
B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS}$	= 0V	40	-	-	V
	Zero Gate Voltage Drain Current	$V_{DS} = 32V$,		-	-	1	^
IDSS		$V_{GS} = 0V$	$T_A = 150^{\circ}C$	-	-	250	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	·	-	-	±100	nA

Test Conditions

Min

On Characteristics

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	2.8	4	V
	 	$I_D = 50A, V_{GS} = 10V$	-	6.7	8.7	mΩ
r _{DS(on)}		$I_D = 50A, V_{GS} = 10V$ $T_J = 175$ °C	-	12.5	16.3	

Dynamic Characteristics

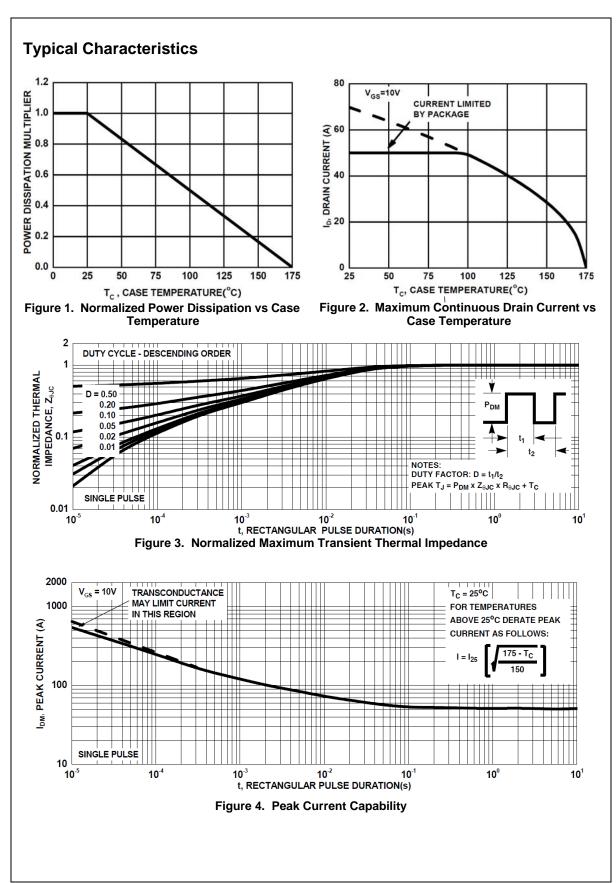
C _{iss}	Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ - f = 1MHz		-	3040	4050	pF
C _{oss}	Output Capacitance			-	295	390	pF
C _{rss}	Reverse Transfer Capacitance			-	178	270	pF
R_G	Gate Resistance	f = 1MHz		-	1.7	-	Ω
$Q_{g(TOT)}$	Total Gate Charge at 10V	V _{GS} = 0 to 10V		-	45	59	nC
$Q_{g(TH)}$	Threshold Gate Charge	$V_{GS} = 0$ to $2V$	$V_{DD} = 20V$		5.8	7.6	nC
Q _{gs}	Gate to Source Gate Charge		$I_{D} = 50A$	-	12.5	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	10.5	-	nC

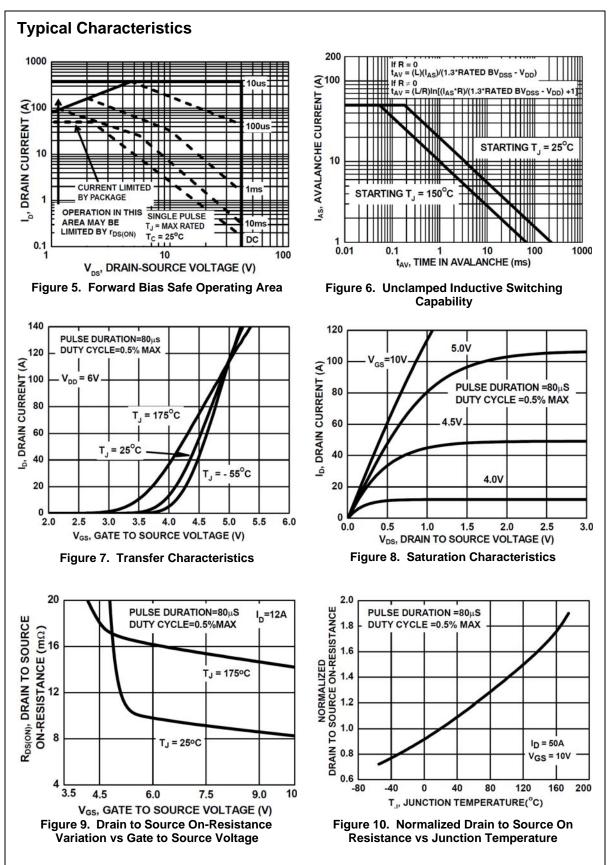
Switching Characteristics

t _{on}	Turn-On Time	$V_{DD} = 20V, I_D = 50A$ $V_{GS} = 10V, R_{GS} = 2\Omega$	-	-	138	ns
t _{d(on)}	Turn-On Delay Time		-	10	-	ns
t _r	Rise Time		ı	82	-	ns
t _{d(off)}	Turn-Off Delay Time		-	26	-	ns
t _f	Fall Time		-	9.6	-	ns
t _{off}	Turn-Off Time		-	-	53	ns

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	I _{SD} = 50A	-	-	1.25	V
	Source to Drain Diode Voltage	$I_{SD} = 25A$	-	-	1.0	
t _{rr}	Reverse Recovery Time	1 - 500 dl /dt - 1000/	-	-	39	ns
Q_{rr}	Reverse Recovery Charge	$I_{SD} = 50A$, $dI_{SD}/dt = 100A/\mu s$	-	-	38	nC





Typical Characteristics

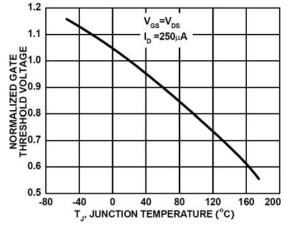


Figure 11. Normalized Gate Threshold Voltage vs **Junction Temperature**

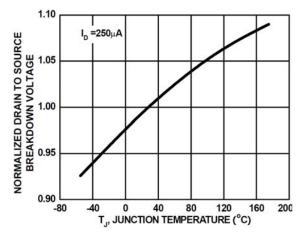


Figure 12. Normalized Drain to Source **Breakdown Voltage vs Junction Temperature**

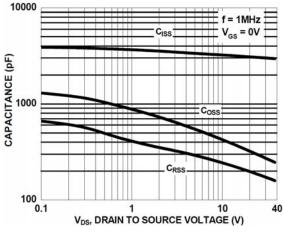


Figure 13. Capacitance vs Drain to Source Voltage

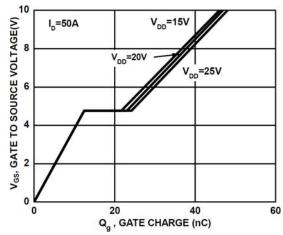


Figure 14. Gate Charge vs Gate to Source Voltage

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